General Description

The MAX4524/MAX4525 are low-voltage, single-supply CMOS analog switches configured as a 4-channel multiplexer/demultiplexer (MAX4524) and a double-pole/double-throw (DPDT) switch (MAX4525). Both have an inhibit input to simultaneously open all signal paths.

These devices operate from a single supply of +2V to +12V and are optimized for operation with +3V or +5V supplies. On-resistance is 200Ω with a +5V supply and 500Ω with a +3V supply. Each switch can handle Rail-to-Rail analog signals. The off-leakage current is only 2nA at +25°C or 20nA at +85°C.

All digital inputs have 0.8V to 2.4V logic thresholds, ensuring TTL/CMOS-logic compatibility when using a single +5V supply.

_Applications

Battery-Operated Equipment Audio and Video Signal Routing Low-Voltage Data-Acquisition Systems Communications Circuits

Features

- Tiny 10-Pin TDFN Package
- Single-Supply Operation from +2V to +12V
- ♦ 200Ω On-Resistance with +5V Supply
- ♦ 500Ω On-Resistance with +3V Supply
- Guaranteed 8Ω On-Resistance Match at +5V
- Guaranteed 2nA Max On-Leakage at +5V
- TTL/CMOS-Logic Compatible

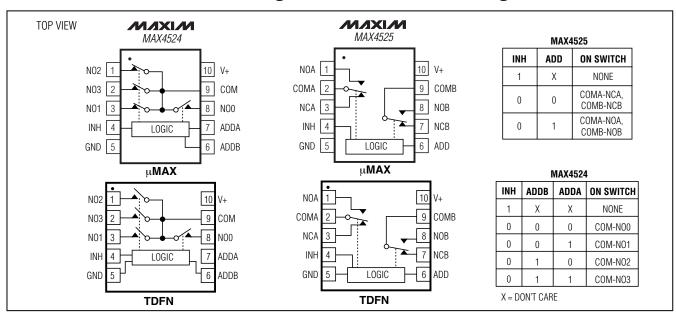
_Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK	
MAX4524CUB	0°C to +70°C	10 µMAX	_	
MAX4524C/D	0°C to +70°C	Dice*	_	
MAX4524EUB	-40°C to +85°C	10 µMAX	_	
MAX4524ETB	-40°C to +85°C	10 TDFN-EP** (3mm x 3mm)	AAP	
MAX4525CUB	0°C to +70°C	10 µMAX	_	
MAX4525C/D	0°C to +70°C	Dice*	_	
MAX4525EUB	-40°C to +85°C	10 µMAX	_	
MAX4525ETB	-40°C to +85°C	10 TDFN-EP** (3mm x 3mm)	AAQ	

*Contact factory for availability.

**EP = Exposed Pad.

Pin Configurations/Functional Diagrams/Truth Tables



Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to GND)	Continuous Power Dissipation ($T_A = +70^{\circ}C$)
V+0.3V, +13V	10-Pin μMAX (derate 4.1mW/°C above +70°C)330mW
Voltage into any terminal (Note 1)0.3V to (V+ + 0.3V)	10-Pin TDFN (derate 24.4mW/°C above +70°C)1951mW
Continuous Current into any Terminal	Operating Temperature Ranges
Peak Current, NO, NC or COM_	MAX452_C0°C to +70°C
(pulsed at 1ms,10% duty cycle)±40mA	MAX452_E40°C to +85°C
ESD per Method 3015.7>2000V	Storage Temperature Range65°C to +150°C

Note 1: Voltages exceeding V+ or GND on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = 4.5V to 5.5V, GND = 0V, VAH = 2.4V, VAL = 0.8V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C.$) (Notes 2, 7)

PARAMETER	SYMBOL	CONDITIONS	ТЕМР	MIN	TYP (Note 2)	МАХ	UNITS	
ANALOG SWITCH	1							1
Analog Signal Range	V _{COM} , V _{NO}			C, E	V-		V+	V
COM-NO/NC On-Resistance	Ron	V+ = 4.5V, I _{COM} = 1mA, V _{COM} =	1 4 5V loov 1mA Voor 2 5V			90	150	Ω
COM NO/NO ON NESIStance	TON		- 0.0 V	C, E			200	52
COM-NO/NC On-Resistance Match Between Channels	ΔR _{ON}	V+ = 4.5V, I _{COM} = 1mA, V _{COM} =	= 3.5V	+25°C		2	10	Ω
(Note 3)	_			C, E			15	
COM-NO/NC On-Resistance Flatness (Note 4)	R _{FLAT}	V+ = 5.5V; I _{COM} = 1mA; V _{COM} = 1.5V, 2.5V, 3.5V				5	12	Ω
NO/NC Off-Leakage	INO(OFF),				-1		+1	
(Note 5)	INC(OFF),	$V + = 5.5V; V_{NO} = 1V, 4.5V; V_{CC}$	M = 4.5V, IV	C, E	-10		+10	nA
		$V_{COM} = 4.5V, 1V$		+25°C	-2		+2	nA
COM Off-Leakage			MAX4524	C, E	-50		+50	
(Note 5)	ICOM(OFF)		MAX4525	+25°C	-1		+1	
			IVIAX4525	C, E	-25		+25	
			MAX4524	+25°C	-2		+2	nA
COM On-Leakage		V+ = 5.5V; V _{COM} = 4.5V, 1V	IVIAA4024	C, E	-50		+50	
(Note 5)	ICOM(ON)	$v + = 5.5v, v_{COM} = 4.5v, 1v$	-	+25°C	-1		+1	
		MAX4525	C, E	-25		+25]	
DIGITAL I/O			•					
Logic Input Logic Threshold High	VIH			C, E		1.5	2.4	V
Logic Input Logic Threshold Low	VIL			C, E	0.8	1.5		V
Input Current High	Ιн	$V_A = V_{INH} = 2.4V$		C, E	-1		+1	μA
Input Current Low	Iн	$V_A = V_{INH} = 0.8V$		C, E	-1		+1	μA

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = 4.5V to 5.5V, GND = 0V, V_{AH} = 2.4V, V_{AL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 7)

PARAMETER	SYMBOL	CONDITIONS	ТЕМР	MIN	TYP (Note 2)	MAX	UNITS		
SWITCH DYNAMIC CHARA	CTERISTICS	6							
Inhibit Turn-On Time	t(ON)		$V_{NO_{-}} = 3V, R_{L} = 300\Omega, C_{L} = 35pF,$			90	150	ns	
	-(011)	Figure 2		C, E			200		
Inhibit Turn-Off Time	t(OFF)	$V_{NO} = 3V, R_L = 300\Omega, C_L = 35$	pF,	+25°C		40	120	ns	
	(011)	Figure 2		C, E			180		
Address Transition Time	TRANS	$V_{NO_{-}} = 3V/0V, R_{L} = 300\Omega, C_{L} =$: 35pF,	+25°C		90	150	ns	
	THANS	Figure 1		C, E			200	115	
Break-Before-Make Time	tBBM	$V_{NO_{-}} = 3V, R_{L} = 300\Omega, C_{L} = 35$	pF, Figure 3	+25°C	5	20		ns	
Charge Injection (Note 6)	Q	C = 1nF, $R_S = 0\Omega$, $V_S = 2.5V$, F	$C = 1nF$, $R_S = 0\Omega$, $V_S = 2.5V$, Figure 4			0.8	5	рС	
NO/NC Off-Capacitance	C _{NO(OFF)}	$V_{NO_{-}} = 0V$, f = 1MHz, Figure 6	V _{NO} = 0V, f = 1MHz, Figure 6			4		pF	
		VALO OV 6 1MHZ FIGURO 6	MAX4524	+25°C		14		~	
COM Off-Capacitance	CCOM(OFF)	V_{NO} = 0V, f = 1MHz, Figure 6	MAX4525	+25°C		6		рF	
COM On-Capacitance	Cookron	$V_{\rm MO} = 0V f = 1 MHz$ Eiguro 6	MAX4524	+25°C		20		pF	
COM ON-Capacitance	CCOM(ON)	$V_{NO} = 0V$, f = 1MHz, Figure 6	MAX4525	+25°C		12			
Off-Isolation	VISO	$R_L = 50\Omega$, f = 1MHz, Figure 5		+25°C		-75		dB	
Channel-to-Channel Crosstalk (MAX4525)	V _{CT}	$R_L = 50\Omega$, f = 1MHz, Figure 5		+25°C		-74		dB	
Total Harmonic Distortion	THD	$R_L = 600\Omega$, $V_{COM} = 2.5Vp-p$, 20Hz to 20kHz		+25°C		0.2		%	
POWER SUPPLY									
Power-Supply Range	V+			C, E	2		12	V	
Power-Supply Current	+	V+ = 5.5V, VADD = VINH = V+ 0	r OV	+25°C	-1		+1	μA	
i owei-ouppiy cuiteilt		v = -3.3v, $v = 0.00 - v = 0.00$		C, E	-10		+10		

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = 2.7V to 3.6V, GND = 0V, V_{AH} = 2.0V, V_{AL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 7)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	МАХ	UNITS
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO}			C, E	V-		V+	V
COM-NO/NC On-Resistance	Ron	RON $V_{+} = 2.7V, I_{COM} = 0.1mA, V_{COM} = 1.5V$		+25°C		190	400	Ω
COM-NO/NC ON-Resistance	NON			C, E			500	52
NO/NC Off-Leakage	INO(OFF),	V+ = 3.6V; V _{NO} = 1V, 3V; V _{COM}			-1		+1	nA
(Note 6)	INC(OFF)	$v + = 3.0v, v_{\rm NO} = 1v, 3v, v_{\rm COM}$	- 3V, IV	C, E	-10		+10	ПА
			MAX4524	+25°C	-2		+2	
COM Off-Leakage (Note 6)		V+ = 3.6V; V _{NO} = 1V, 3V;	IVIAA4324	C, E	-50		+50	nA
	ICOM(OFF)	$V_{COM} = 3V, 1V$		+25°C	-1		+1	ПA
			MAX4525	C, E	-25		+25	

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = 2.7V to 3.6V, GND = 0V, V_{AH} = 2.0V, V_{AL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 7)

PARAMETER	SYMBOL	CONDITIONS		ТЕМР	MIN	TYP (Note 2)	MAX)	UNITS
			MAX4524	+25°C	-2		+2	
COM On-Leakage		V+ = 3.6V; V _{COM} = 3V, 1V	101474324	C, E	-50		+50	— nA
(Note 6)		$v + = 3.0v, v_{COM} = 3v, v_{V}$	MAX4525	+25°C	-1		+1	
			IVIAA4323	C, E	-25		+25	
DIGITAL I/O	·							
Logic Input Logic Threshold High	ViH			C, E		1.0	2.0	V
Logic Input Logic Threshold Low	VIL				0.5	1.0		V
Input Current High	Ін	$V_A = V_{INH} = 2.0V$		C, E	-1		+1	μA
Input Current Low	Ιн	$V_A = V_{INH} = 0.5V$		C, E	-1		+1	μA
SWITCH DYNAMIC CHAR	ACTERISTIC	S (Note 6)						
Inhibit Turn-On Time	t(ON)	$V_{NO_{-}} = 1.5V, R_{L} = 300\Omega, C_{L} =$: 35pF,	+25°C		170	300	ns
	(ON)	Figure 2		C, E			400	115
Inhibit Turn-Off Time	t(OFF)	$V_{NO_{-}} = 1.5V, R_{L} = 300\Omega, C_{L} =$	- 35pF,	+25°C 50 200	ns			
	(OFF)	Figure 2		C, E			300	115
Address Transition Time	t TRANS	$V_{NO} = 1.5V/0V, R_L = 300\Omega, C_L = 35pF, +25°C$	+25°C		130	300	ns	
Address transmort time	TRANS	Figure 1		C, E			400	115
Break-Before-Make Time	tBBM	Figure 3, V_{NO} = 1.5V, R_L = 300 Ω , C_L = 35pF		+25°C	5	40		ns
POWER SUPPLY								
Power-Supply Current	+	V+ = 3.6V. VADD = VINH = V+	or OV	+25°C	-1		+1	1μA
r ower-Supply Currell	1+	v + = 3.0v, vADD = vINH = v + 0r UV		C, E	-10		+10	μΑ

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 3: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$

Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges; i.e., V_{NO} = 3V to 0V and 0V to 3V.

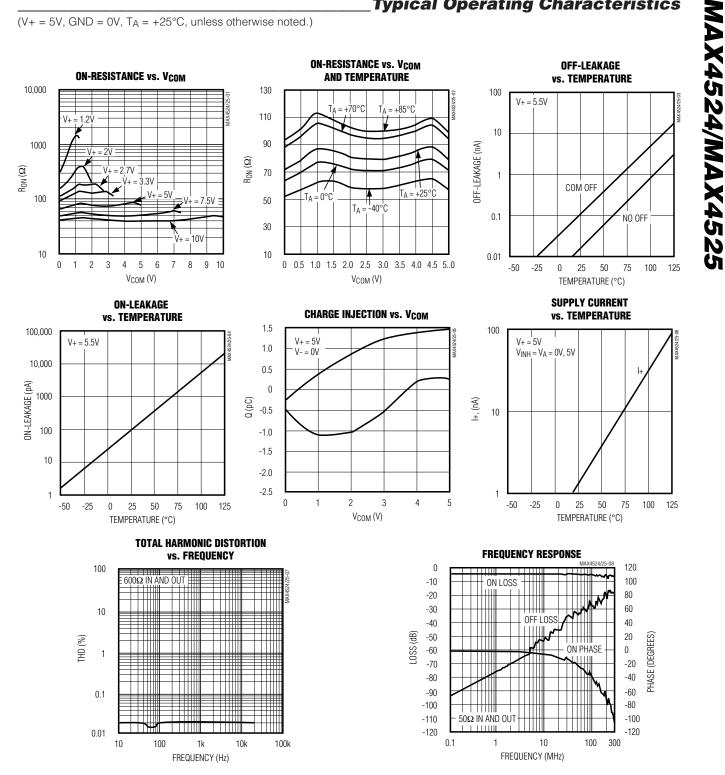
Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature, and guaranteed by correlation at $T_A = +25^{\circ}C$.

Note 6: Guaranteed by design, not production tested.

Note 7: TDFN parts are tested at +25°C and are guaranteed by design and correlation over the entire temperature range.

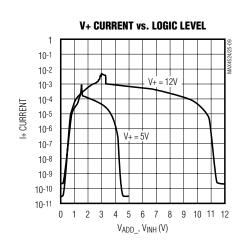
Typical Operating Characteristics

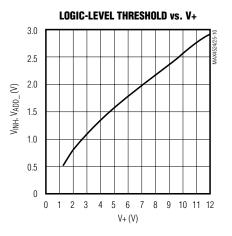
(V+ = 5V, GND = 0V, T_A = +25°C, unless otherwise noted.)



Typical Operating Characteristics (continued)

 $(V + = +5V, GND = 0V, T_A = +25^{\circ}C, unless otherwise noted.)$





Pin Description

MAX4524	MAX4525	NAME	FUNCTION
1		NO2	Analog Switch Normally Open Input 2
	1	NOA	Analog Switch "A" Normally Open Input
2		NO3	Analog Switch Normally Open Input 3
	2	COMA	Analog Switch "A" Common
3		NO1	Analog Switch Normally Open Input 1
_	3	NCA	Analog Switch "A" Normally Closed Input
4	4	INH	Inhibit. Connect to GND for normal operation. Connect to logic-level high to turn all switches off.
5	5	GND	Ground. Connect to digital ground (analog signals have no ground reference, but are limited to V+ and GND).
6		ADDB	Logic-Level Address Input (see Truth Tables)
_	6	ADD	Logic-Level Address Input (see Truth Tables)
7		ADDA	Logic-Level Address Input (see Truth Tables)
_	7	NCB	Analog Switch "B" Normally Closed Input
8		NO0	Analog Switch Normally Open Input 0
_	8	NOB	Analog Switch "B" Normally Open Input
9		COM	Analog Switch Common
_	9	COMB	Analog Switch "A" Common
10	10	V+	Positive Analog and Digital Supply-Voltage Input
EP	EP	EP	TDFN Package Only. Exposed pad, connect to V+.

Note: NO_, NC_, and COM_ analog signal pins are identical and interchangeable. Any may be considered an input or output; signals pass equally well in both directions.

____ /N/XI/N

MAX4524/MAX4525

Low-Voltage, Single-Supply Multiplexer and Switch

Applications Information

Power-Supply Considerations

The MAX4524/MAX4525's construction is typical of most CMOS analog switches. They have two supply pins: V+ and GND. V+ and GND are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog signal pin and both V+ and GND. If any analog signal exceeds V+ or GND, one of these diodes will conduct. During normal operation, these (and other) reversebiased ESD diodes leak, forming the only current drawn from V+ or GND. Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical, and therefore fairly well balanced, they are reverse-biased differently. Each is biased by either V+ or GND and the analog signal. This means that leakage will vary as the signal varies. The difference in the two diode leakages to the V+ and GND pins constitutes the analog signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

V+ V+ 50% Vadd V+ ΔΠΠΔ N00 V ٥V ADDB N01-N02 50OV_{NO0} **MIXIM** 90% 90% MAX4524 NO3 INH СОМ V_{OUT} GND VOUT 35pF 300Ω ٥V **t**TRANS trrans -V+ V+ 50% VADD V+ VADD ADD NO ٥V VNC ΜΙΧΙΜ 90% MAX4525 90% NC V-INH СОМ VOUT GND VOUT 35pF 300Ω OV trrans -**TRANS** REPEAT TEST FOR EACH SECTION.

Test Circuits/Timing Diagrams

Figure 1. Address Transition Time



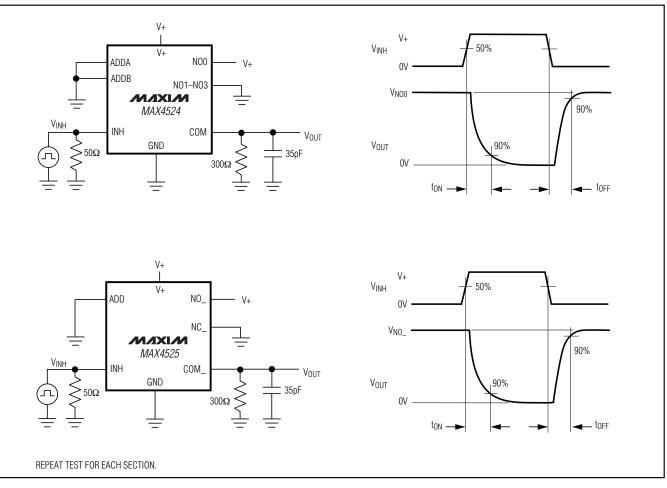
There is no connection between the analog signal paths and GND. V+ and GND power the internal logic and logic-level translators, and set both the input and output logic limits. The logic-level translators convert the logic levels into switched V+ and GND signals to drive the gates of the analog signals. This drive signal is the only connection between the logic supplies (and signals) and the analog supplies. V+ has an ESD-protection diode to GND.

Low-Voltage Operation

These devices operate from a single supply between +2V and +12V. At room temperature, they actually "work" with a single supply at near or below +1.7V, although as supply voltage decreases, switch on-resistance and switching times become very high.

High-Frequency Performance

In 50 Ω systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on-response has several minor peaks, which are highly layout dependent. The problem is not turning the switch on, but turning it off. The off-state switch acts like a capacitor, and passes higher frequencies with less attenuation. At 10MHz, off-isolation is about -50dB in 50 Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also degrade off-isolation. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is entirely due to capacitive coupling.



Test Circuits/Timing Diagrams (continued)

Figure 2. Inhibit Switching Times

M/IXI/M

Test Circuits/Timing Diagrams (continued)

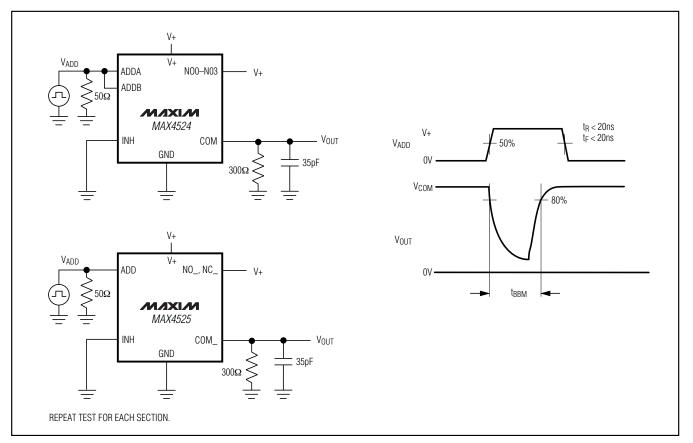


Figure 3. Break-Before-Make Interval

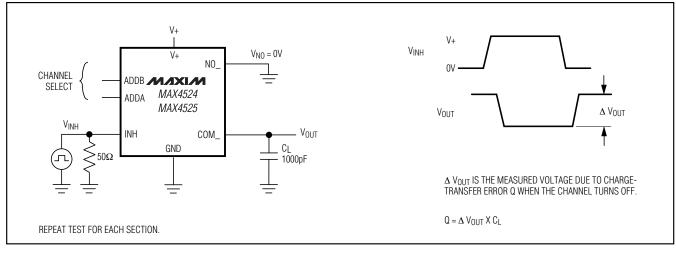


Figure 4. Charge Injection

MAX4524/MAX4525

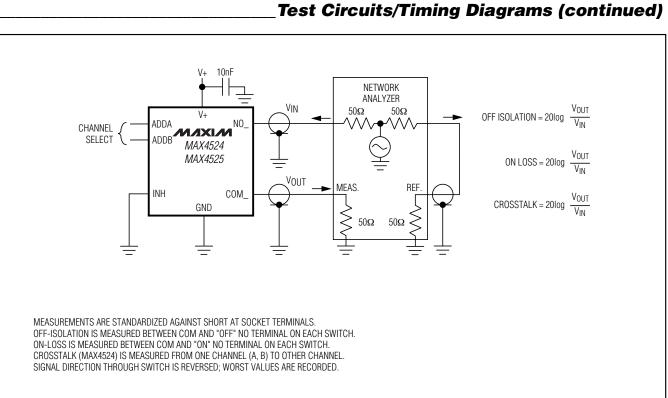


Figure 5. Off-Isolation, On-Loss, and Crosstalk

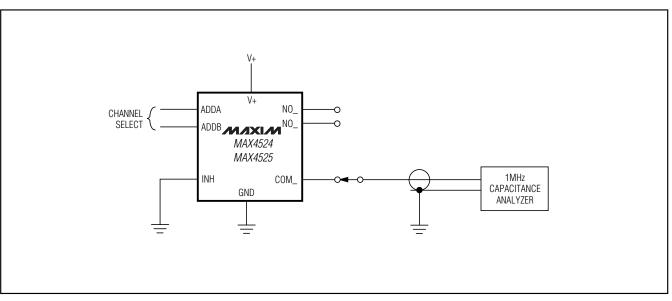
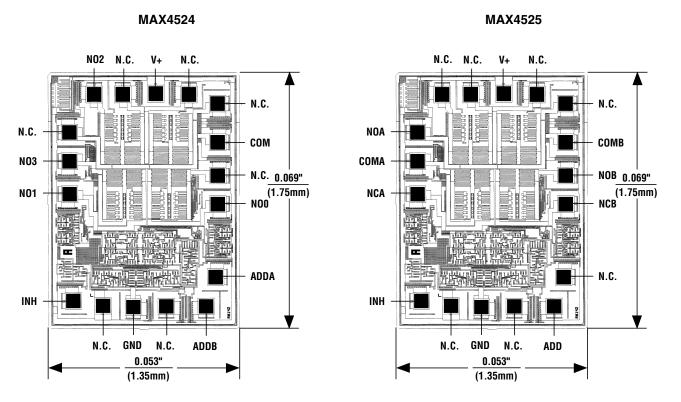


Figure 6. NO/COM Capacitance

MIXIM

_Chip Topographies

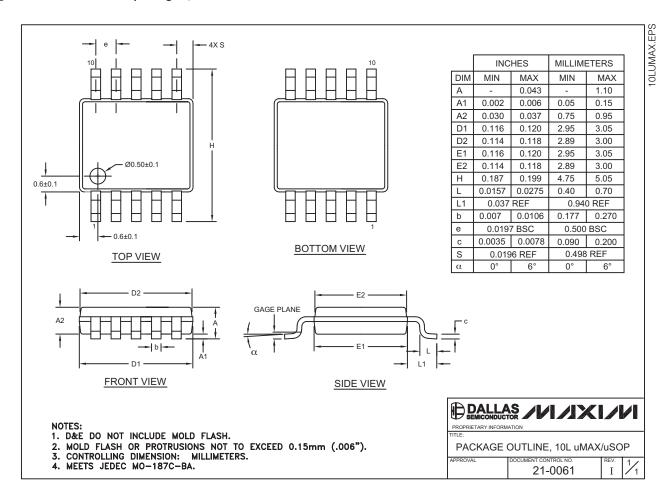


N.C. = No Connection

TRANSISTOR COUNT: 219 SUBSTRATE CONNECTED TO V+

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)



MAX4524/MAX4525

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)

